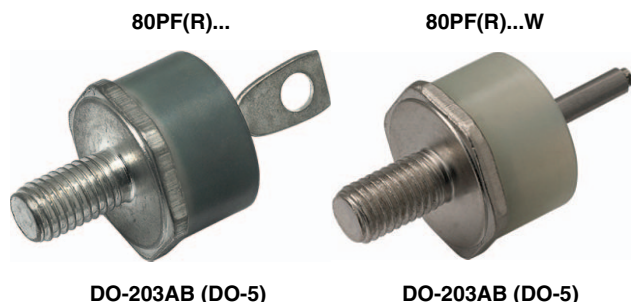


Standard Recovery Diodes, Generation 2 DO-5 (Stud Version), 80 A



DO-203AB (DO-5)

DO-203AB (DO-5)

FEATURES

- High surge current capability
- Designed for a wide range of applications
- Stud cathode and stud anode version
- Wire version available
- Low thermal resistance
- Designed and qualified for multiple level
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912


RoHS
COMPLIANT

TYPICAL APPLICATIONS

- Battery charges
- Converters
- Power supplies
- Machine tool controls
- Welding

PRODUCT SUMMARY

$I_{F(AV)}$	80 A
Package	DO-203AB (DO-5)
Circuit configuration	Single diode

MAJOR RATINGS AND CHARACTERISTICS

PARAMETER	TEST CONDITIONS	VALUES	UNITS
$I_{F(AV)}$		80	A
	T_C	123	°C
$I_{F(RMS)}$		126	A
I_{FSM}	50 Hz	1200	A
	60 Hz	1250	
I^2t	50 Hz	7100	A ² s
	60 Hz	6450	
V_{RRM}	Range	1400 to 1600	V
T_J		-55 to 150	°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS

TYPE NUMBER	VOLTAGE CODE	V_{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} MAXIMUM AT $T_J = 150\text{ °C}$ mA
VS-80PF(R)...(W)	140	1400	1650	4.5
	160	1600	1900	



FORWARD CONDUCTION							
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS	
Maximum average forward current at case temperature	I _{F(AV)}	180° conduction, half sine wave			80	A	
					123	°C	
Maximum RMS forward current	I _{F(RMS)}				126	A	
Maximum peak, one-cycle forward, non-repetitive surge current	I _{FSM}	t = 10 ms	No voltage reapplied	Sinusoidal half wave, initial T _J = 150 °C	1200	A	
		t = 8.3 ms			1250		
		t = 10 ms	100 % V _{RRM} reapplied		1000		
		t = 8.3 ms			1050		
Maximum I ² t for fusing	I ² t	t = 10 ms	No voltage reapplied			7100	A ² s
		t = 8.3 ms				6450	
		t = 10 ms	100 % V _{RRM} reapplied			5000	
		t = 8.3 ms				4550	
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied			71 000	A ² √s	
Low level value of threshold voltage	V _{F(TO)}	(16.7 % × π × I _{F(AV)}) < I < π × I _{F(AV)} , T _J = T _J maximum			0.73	V	
Low level value of forward slope resistance	r _f	(16.7 % × π × I _{F(AV)}) < I < π × I _{F(AV)} , T _J = T _J maximum			3.0	mΩ	
Maximum forward voltage drop	V _{FM}	I _{pk} = 220 A, T _J = 25 °C, t _p = 400 μs rectangular wave			1.46	V	

THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction operating and storage temperature range	T_J, T_{Stg}		-55 to 180	°C
Maximum thermal resistance, junction to case	R_{thJC}	DC operation	0.30	K/W
Maximum thermal resistance, case to heatsink	R_{thCS}	Mounting surface, smooth, flat and greased	0.25	
Allowable mounting torque		Not lubricated threads, tightening on nut ⁽¹⁾	3.4 (30)	N · m (lbf · in)
		Lubricated threads, tightening on nut ⁽¹⁾	2.3 (20)	
		Not lubricated threads, tightening on Hexagon ⁽²⁾	4.2 (37)	
		Lubricated threads, tightening on Hexagon ⁽²⁾	3.2 (28)	
Approximate weight			15.8	g
			0.56	oz.
Case style		See dimensions - link at the end of datasheet	DO-203AB (DO-5)	

Notes

- (1) Recommended for pass-through holes
 (2) Torque must be applicable only to Hexagon and not to plastic structure, recommended for holed heatsink

ΔR_{thJC} CONDUCTION				
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.14	0.10	$T_J = T_J$ maximum	K/W
120°	0.16	0.17		
90°	0.21	0.22		
60°	0.30	0.31		
30°	0.50	0.50		

Note

- The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

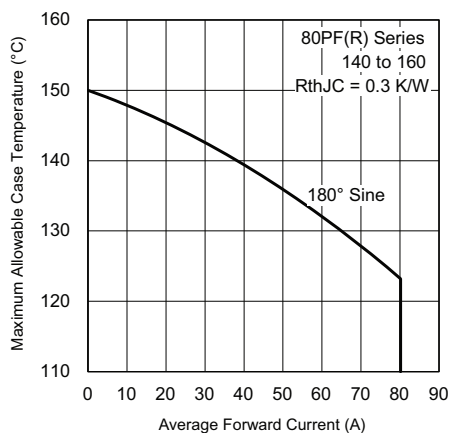


Fig. 1 - Current Ratings Characteristics

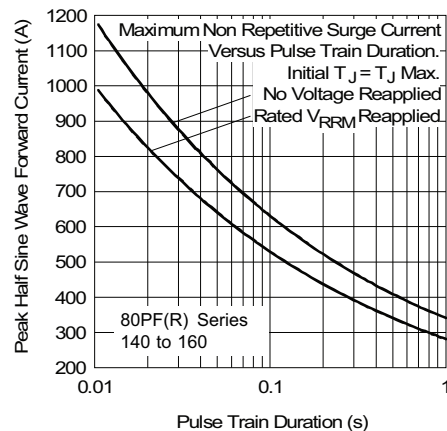


Fig. 3 - Forward Power Loss Characteristics

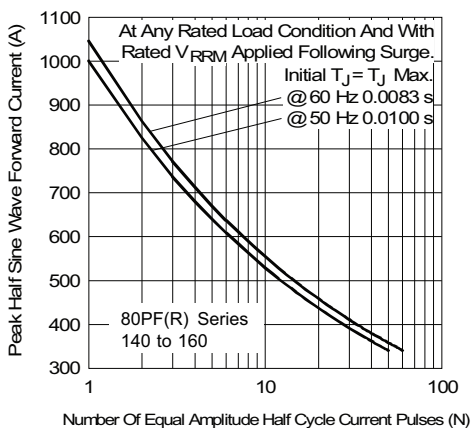


Fig. 2 - Current Ratings Characteristics

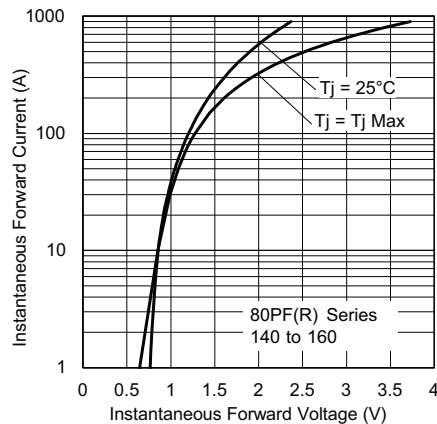


Fig. 4 - Forward Power Loss Characteristics

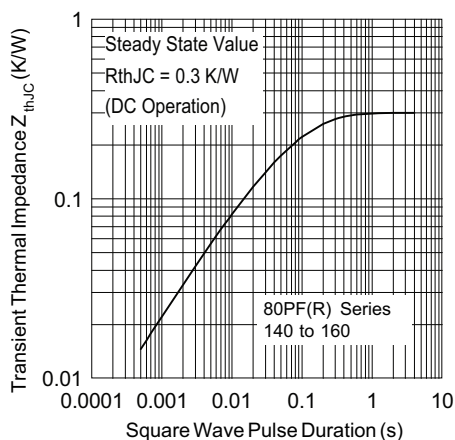


Fig. 5 - Maximum Non-Repetitive Surge Current



ORDERING INFORMATION TABLE

Device code	VS-	80	PF	R	160	W
	1	2	3	4	5	6

- | | | |
|----------|---|---|
| 1 | - | Vishay Semiconductors product |
| 2 | - | 80 = Standard device |
| 3 | - | PF = Plastic package |
| 4 | - | <ul style="list-style-type: none">• None = Stud normal polarity (cathode to stud)• R = Stud reverse polarity (anode to stud) |
| 5 | - | Voltage code x 10 = V_{RRM} (see Voltage Ratings table) |
| 6 | - | <ul style="list-style-type: none">• None = Standard terminal
(see dimensions for 80PF(R)... - link at the end of datasheet)• W = Wire terminal
(see dimensions for 80PF(R)...W - link at the end of datasheet) |

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95345



DO-203AB (DO-5) for 50PF(R)...(W), 80PF(R)...(W), and 95PF(R)...(W) Series

DIMENSIONS FOR 80PF(R), 50PF(R) AND 95PF(R) SERIES in millimeters



Note

- For metric device please contact factory



DIMENSIONS FOR 80PF(R)...(W), 50PF(R)...(W) AND 95PF(R)...(W) SERIES in millimeters

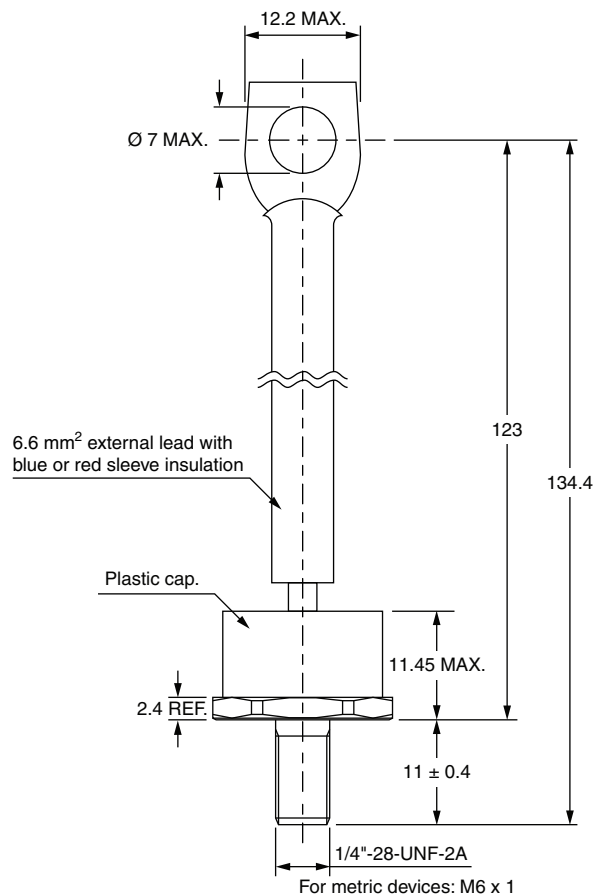


Note

- For metric device please contact factory



DIMENSIONS FOR 52PF(R), 82PF(R) AND 97PF(R) SERIES in millimeters



Note

- For metric device please contact factory



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